Notice of References Cited Application/Control No. 10/682,128 Applicant(s)/Patent Under Reexamination KIM, SUNG-HO Examiner Anh D. Mai 2814 Page 1 of 1

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	Α	US-5,168,465 A	12-1992	Harari, Eliyahou	257/320
	В	US-6,429,472 B2	08-2002	Kim et al.	257/295
	С	US-6,791,140 B2	09-2004	Prall, Kirk D.	257/315
	D	US-6,828,618 B2	12-2004	Baker et al.	257/311
	Е	US-			
	F	US-			
	G	US-			
	Н	US-			
	-	US-			
	J	US-			
	к	US-			
	L	US-			,
	М	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	0					
	P					
	O					
	R					
	S					
	Т					

NON-PATENT DOCUMENTS

* Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)						
	U	M.L. French et al., Design and Scalling of a SONOS Multidielectric Device for Nonvolatile Memory Applications. IEEE 1994, pp. 390-397.				
	٧	M. H. White et al., A Low Voltage SONOS Nonvolatile Semiconductor Memory Technology. IEEE 1996, pp. 52-57.				
	w					
	х	_				

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)

Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.